

400Gb/s QSFP-DD FR4 2km Transceiver

LA-OT-400G-FR4

Description

This product is a 400Gb/s Quad Small Form Factor Pluggable-double density (QSFP-DD) optical module designed for 2km optical communication applications. The module converts 8 channels of 50Gb/s (PAM4) electrical input data to 4 channels of CWDM optical signals, and multiplexes them into a single channel for 400Gb/s optical transmission. Reversely, on the receiver side, the module optically de-multiplexes a 400Gb/s optical input into 4 channels of CWDM optical signals, and converts them to 8 channels of 50Gb/s (PAM4) electrical output data. The central wavelengths of the 4 CWDM channels are 1271, 1291, 1311 and 1331 nm as members of the CWDM wavelength grid defined in ITU-T G.694.2. It contains a duplex LC connector for the optical interface and a 76-pin connector for the electrical interface. To minimize the optical dispersion in the long-haul system, single-mode fiber (SMF) has to be applied in this module. Host FEC is required to support up to 2km fiber transmission The product is designed with form factor, optical/electrical connection and digital diagnostic interface according to the QSFP-DD Multi-Source Agreement (MSA) Type 2. It has been designed to meet the harshest external operating conditions including temperature, humidity and EMI interference.

Features

- QSFP-DD MSA compliant
- 4 CWDM lanes MUX/DEMUX design
- 100G Lambda MSA 400G-FR4 Specification compliant
- Up to 2km transmission on single mode fiber (SMF) with FEC
- Operating case temperature: 0 to 70oC
- 8x53.125Gb/s electrical interface (400GAUI-8)
- Data Rate 106.25Gbps (PAM4) per channel.
- Maximum power consumption 12W
- Duplex LC connector
- RoHS compliant

Applications

- Data Center Interconnect
- 400G Fthernet
- Infiniband interconnects
- Enterprise networking



Transceiver Block Diagram

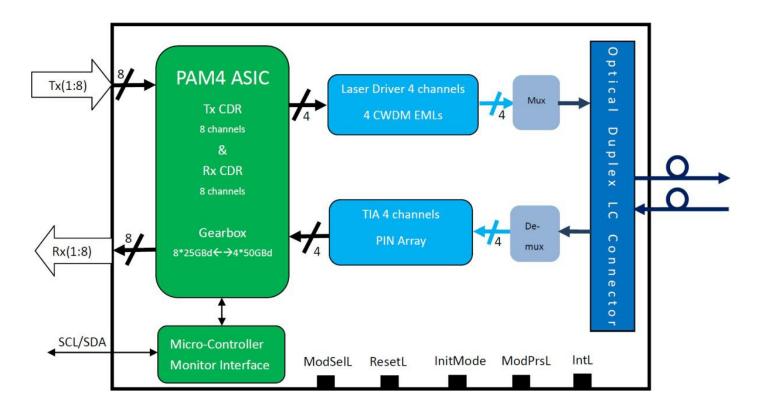


Figure 1. Transceiver Block Diagram



Pin Assignment and Description

The electrical pinout of the QSFP-DD module is shown in Figure 2 below.

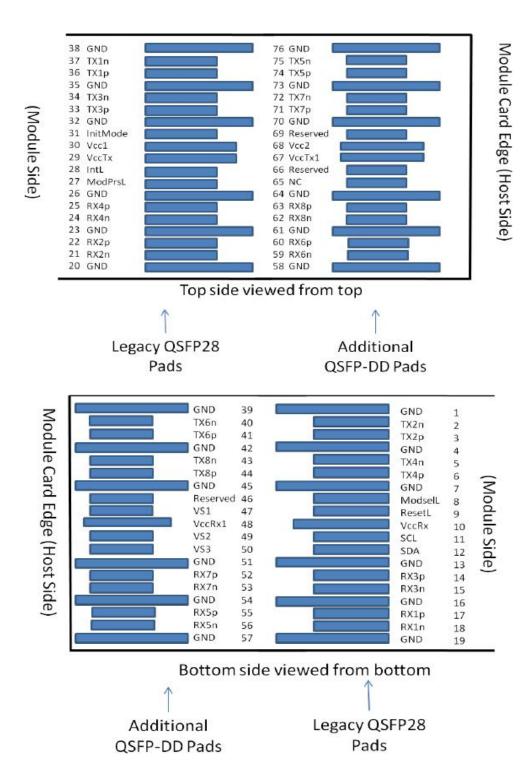


Figure 2. MSA Compliant Connector



Pin Definition

Pin	Logic	Symbol	Description	Plug Sequence	Notes
1		GND	Ground	1B	1
2	CML-I	Tx2n	Transmitter Inverted Data Input	3B	
3	CML-I	Tx2p	Transmitter Non-Inverted Data	3B	
			Input		
4		GND	Ground	Ground 1B	
5	CML-I	Tx4n	Transmitter Inverted Data Input	3B	
6	CML-I	Тх4р	Transmitter Non-Inverted Data	3B	
			Input		
7		GND	Ground	1B	1
8	LVTTL-I	ModSelL	Module Select	3B	
9	LVTTL-I	ResetL	Module Reset	3B	
10		VccRx	+3.3V Power Supply Receiver	2B	2
11	LVCMOS-	SCL	2-wire serial interface clock	3B	
	I/O				
12	LVCMOS-	SDA	2-wire serial interface data	3B	
	I/O				
13		GND	Ground	1B	1
14	CML-O	Rx3p	Receiver Non-Inverted Data Output	3B	
15	CML-O	Rx3n	Receiver Inverted Data Output	3B	
16	GND	Ground	1B		1
17	CML-O	Rx1p	Receiver Non-Inverted Data Output	3B	
18	CML-O	Rx1n	Receiver Inverted Data Output	3B	
19		GND	Ground	1B	1
20		GND	Ground	1B	1
21	CML-O	Rx2n	Receiver Inverted Data Output	3B	
22	CML-O	Rx2p	Receiver Non-Inverted Data Output	3B	
23		GND	Ground	1B	1
24	CML-O	Rx4n	Receiver Inverted Data Output	3B	
25	CML-O	Rx4p	Receiver Non-Inverted Data Output	3B	
26		GND	Ground	Ground 1B	
27	LVTTL-O	ModPrsL	Module Present	3B	



28	LVTTL-O	IntL	Interrupt	3B	
29		VccTx	+3.3V Power supply transmitter 2B		2
30		Vcc1	+3.3V Power supply	2B	2
31	LVTTL-I	InitMode	Initialization mode; In legacy QSFP	3B	
			applications, the InitMode pad is		
			called LPMODE		
32		GND	Ground	1B	1
33	CML-I	Тх3р	Transmitter Non-Inverted Data	3B	
			Input		
34	CML-I	Tx3n	Transmitter Inverted Data Input	3B	
35		GND	Ground	1B	1
36	CML-I	Tx1p	Transmitter Non-Inverted Data	3B	
			Input		
37	CML-I	Tx1n	Transmitter Inverted Data Input	3B	
38		GND	Ground	1B	1
39		GND	Ground	1A	1
40	CML-I	Tx6n	Transmitter Inverted Data Input	3A	
41	CML-I	Тх6р	Transmitter Non-Inverted Data	3A	
			Input		
42		GND	Ground	1A	1
43	CML-I	Tx8n	Transmitter Inverted Data Input	3A	
44	CML-I	Тх8р	Transmitter Non-Inverted Data	3A	
			Input		
45		GND	Ground	1A	1
46		Reserved	For future use	3A	3
47		VS1	Module Vendor Specific 1	3A	3
48		VccRx1	3.3V Power Supply	2A	2
49		VS2	Module Vendor Specific 2 3A		3
50		VS3	Module Vendor Specific 3 3A		3
51		GND	Ground	1A	1



52	CML-O	Rx7p	Receiver Non-Inverted Data Output	3A	
53	CML-O	Rx7n	Receiver Inverted Data Output	3A	
54		GND	Ground	1A	1
55	CML-O	Rx5p	Receiver Non-Inverted Data Output	3A	
56	CML-O	Rx5n	Receiver Inverted Data Output	3A	
57		GND	Ground	1A	1
58		GND	Ground	1A	1
59	CML-O	Rx6n	Receiver Inverted Data Output	3A	
60	CML-O	Rx6p	Receiver Non-Inverted Data Output	3A	
61		GND	Ground	1A	1
62	CML-O	Rx8n	Receiver Inverted Data Output	3A	
63	CML-O	Rx8p	Receiver Non-Inverted Data Output	3A	
64		GND	Ground	1A	1
65		NC	No Connect	3A	3
66		Reserved	For future use	3A	3
67		VccTx1	3.3V Power Supply	2A	2
68		Vcc2	3.3V Power Supply	2A	2
69		Reserved	For Future Use	3A	3
70		GND	Ground	1A	1
71	CML-I	Тх7р	Transmitter Non-Inverted DataInput	3A	
72	CML-I	Tx7n	Transmitter Inverted Data Input	3A	
73		GND	Ground	1A	1
74	CML-I	Тх5р	Transmitter Non-Inverted DataInput	3A	
75	CML-I	Tx5n	Transmitter Inverted Data Input	3A	
76		GND	Ground	1A	1



Recommended Power Supply Filter

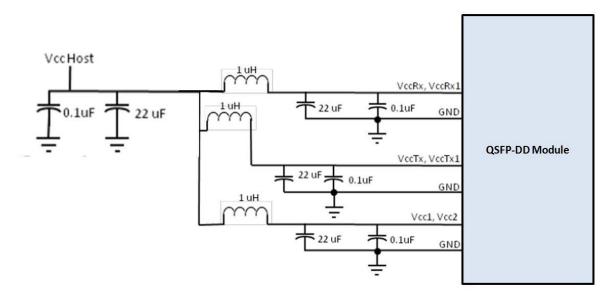


Figure 3. Recommended Power Supply Filter

Absolute Maximum Ratings

It has to be noted that the operation in excess of any individual absolute maximum ratingsmight cause permanent damage to this module.

Parameter	Symbol	Min	Max	Units	Notes
Storage Temperature	TS	-40	85	degC	
Operating Case Temperature	ТОР	0	70	degC	
Power Supply Voltage	VCC	-0.5	3.6	V	
Relative Humidity (non-condensation)	RH	0	85	%	
Damage Threshold, each Lane	TH _d	4.5		dBm	



Recommended Operating Conditions and Power Supply Requirements

Parameter	Symbol	Min	Typical	Max	Units	Notes
Operating Case Temperature	ТОР	0		70	degC	
Power Supply Voltage	VCC	3.135	3.3	3.465	V	
Data Rate, each Lane			26.5625		GBd	PAM4
Data Rate Accuracy		-100		100	ppm	
Pre-FEC Bit Error Ratio				2.4x10 ⁻⁴		
Post-FEC Bit Error Ratio				1x10 ⁻¹²		1
Link Distance	D	0.002		2	km	2

Notes:

- 1. FEC provided by host system.
- 2. FEC required on host system to support maximum distance.

Electrical Characteristics

The following electrical characteristics are defined over the Recommended OperatingEnvironment unless otherwise specified.

Parameter	Test Point	Min	Typical	Max	Units	Notes
Power Consumption				12	W	
Supply Current	Icc			3.64	А	
		Transmitter (each Lane)				
Signaling Rate, each Lane	TP1	26.5625 ± 100 ppm			GBd	
Differential pk-pk Input Voltage Tolerance	TP1a	900			mVpp	1
Differential Termination Mismatch	TP1			10	%	
Differential Input Return Loss	TP1	IEEE 802.3-2015 Equation (83E-5)			dB	
Differential to Common Mode Input Return Loss	TP1	IEEE 802.3- 2015			dB	
		Equation (83E-6)				



Module Stressed Input Test	TP1a	See IEEE 802.3bs 120E.3.4.1				2
Single-ended Voltage Tolerance Range (Min)	TP1a	-0.4 to 3.3			V	
DC Common Mode Input Voltage	TP1	-350		2850	mV	3
	Rec	eiver (each Lane)				
Signaling Rate, each lane	TP4	26.562	5 ± 100 ppm		GBd	
Differential Peak-to-Peak Output Voltage	TP4			900	mVpp	
AC Common Mode Output Voltage, RMS	TP4			17.5	mV	
Differential Termination Mismatch	TP4			10	%	
Differential Output ReturnLoss	TP4	2015 Equation (83E-2)				
Common to Differential Mode Conversion ReturnLoss	TP4	2015 Equation (83E-3)				
Transition Time, 20% to 80%	TP4	9.5			ps	
Near-end Eye SymmetryMask Width (ESMW)	TP4		0.265		UI	
Near-end Eye Height, Differential	TP4	70			mV	
Far-end Eye Symmetry MaskWidth (ESMW)	TP4		0.2		UI	
Far-end Eye Height, Differential	TP4	30			mV	
Far-end Pre-cursor ISI Ratio	TP4	-4.5		2.5	%	



Common Mode Output	TP4	-350	2850	mV	3
Voltage (Vcm)	114	330	2030	111 V	

Notes:

- 1. With the exception to IEEE 802.3bs 120E.3.1.2 that the pattern is PRBS31Q or scrambled idle.
- 2. Meets BER specified in IEEE 802.3bs 120E.1.1.
- 3. DC common mode voltage generated by the host. Specification includes effects of ground offset voltage.

Optical Characteristics

Parameter	Symbol	Min	Typical	Max	Units	Notes
	LO	1264.5	1271	1277.5	nm	
Wavelength Assignment	L1	1284.5	1291	1297.5	nm	
	L2	1304.5	1311	1317.5	nm	
	L3	1324.5	1331	1337.5	nm	
		Transmitter				
Data Rate, each Lane		53.1	.25 ± 100 ppr	n	GBd	
Modulation Format			PAM4			
Side-mode Suppression Ratio	SMSR	30			dB	
Total Average Launch Power	PŢ			9.3	dBm	
Average Launch Power, each Lane	PAVG	-3.3		3.5	dBm	1
Outer Optical Modulation	POMA	-0.3		3.7	dBm	2
Amplitude (OMAouter), each Lane	POMA	-0.3		3.7	иын	2
Launch Power in OMA _{outer} minus						
TDECQ, each Lane		-1.7			dB	
for ER ≥ 4.5dB		-1.6				
for ER < 4.5dB						
Transmitter and Dispersion Eye	TDECQ			3.4	dB	
Closure for PAM4, each Lane	15200			3.1	45	
TDECQ – 10*log10(Ceq), each Lane				3.4	dB	3
Extinction Ratio	ER	3.5			dB	
Difference in Launch Power						
between any Two Lanes				4	dB	



(OMAouter)						
RIN _{17.1} OMA	RIN			-136	dB/Hz	
Optical Return Loss Tolerance	TOL			17.1	dB	
Transmitter Reflectance	RT			-26	dB	
Transmitter Transition Time				17	ps	
Average Launch Power of OFF Transmitter, each Lane	Poff			-20	dBm	
		Receiver				
Data Rate, each Lane		53.1	25 ± 100 ppr	n	GBd	
Modulation Format			PAM4			
Damage Threshold, each Lane	THd	4.5			dBm	4
Average Receive Power, each Lane		-7.3		3.5	dBm	5
Receive Power (OMA _{outer}), each Lane				3.7	dBm	
Difference in Receiver Power between any Two Lanes (OMAouter)				4.1	dB	
Receiver Sensitivity (OMA _{outer}), each Lane	SEN			Equation (1)	dBm	6
Stressed Receiver Sensitivity (OMA _{outer}), each Lane	SRS			-2.6	dBm	7
Receiver Reflectance	RR			-26	dB	
LOS Assert	LOSA	-20			dBm	
LOS De-assert	LOSD			-10.3	dBm	
LOS Hysteresis	LOSH	0.5			dB	
Stressed C	onditions for	Stress Receiv	ver Sensitivit	y (Note 8)		
Stressed Eye Closure for PAM4			3.4		dB	



(SECQ), Lane under Test					
SECQ – 10*log10(Ceq), Lane underTest			3.4	dB	
OMA _{outer} of each Aggressor Lane		1.5		dBm	
Modulation Format	PAM	14			

Notes:

- 1. Average launch power, each lane (min) is informative and not the principal indicator of signal strength. A transmitter with launch power below this value cannot be compliant; however, a value above this does not ensure compliance.
- 2. Even if the TDECQ < 1.4 dB for an extinction ratio of \geq 4.5 dB or TDECQ < 1.3 dB for an extinction ratio of < 4.5 dB, the OMAouter (min) must exceed the minimum value specified here.
- 3. Ceq is a coefficient defined in IEEE Std 802.3-2018 clause 121.8.5.3 which accounts for reference equalizer noise enhancement.
- 4. Average receive power, each lane (min) is informative and not the principal indicator of signal strength. A received power below this value cannot be compliant; however, a value above this does not ensure compliance.
- 5. The receiver shall be able to tolerate, without damage, continuous exposure to an optical input signal having this average power level.
- 6. Receiver sensitivity (OMAouter) is informative and is defined for a transmitter with a value of SECQ up to 3.4 dB. Receiver sensitivity should meet Equation (1), which is illustrated in Figure 4.

Where:

RS is the receiver sensitivity, and

SECQ is the SECQ of the transmitter used to measure the receiver sensitivity.

7. Measured with conformance test signal at TP3 for the BER equal to 2.4x10-4.



Digital Diagnostic Functions

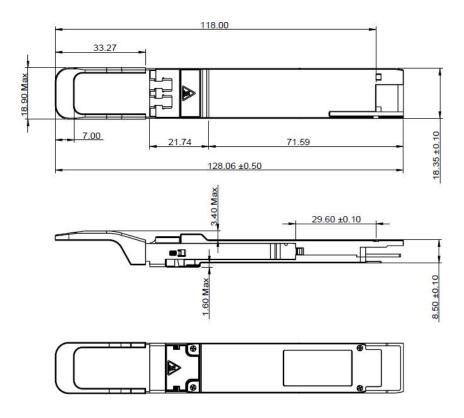
The following digital diagnostic characteristics are defined over the normal operating conditions unless otherwise specified.

Parameter	Symbol	Min	Max	Units	Notes
Temperature Monitor Absolute Error	DMI_Temp	-3	3	degC	Over operating temperature range
Supply Voltage Monitor Absolute Error	DMI_VCC	-0.1	0.1	V	Over full operating range
Channel RX Power Monitor Absolute Error	DMI_RX_Ch	-2	2	dB	1
Channel Bias Current Monitor	DMI_Ibias_Ch	-10%	10%	mA	
Channel TX Power Monitor Absolute Error	DMI_TX_Ch	-2	2	dB	1

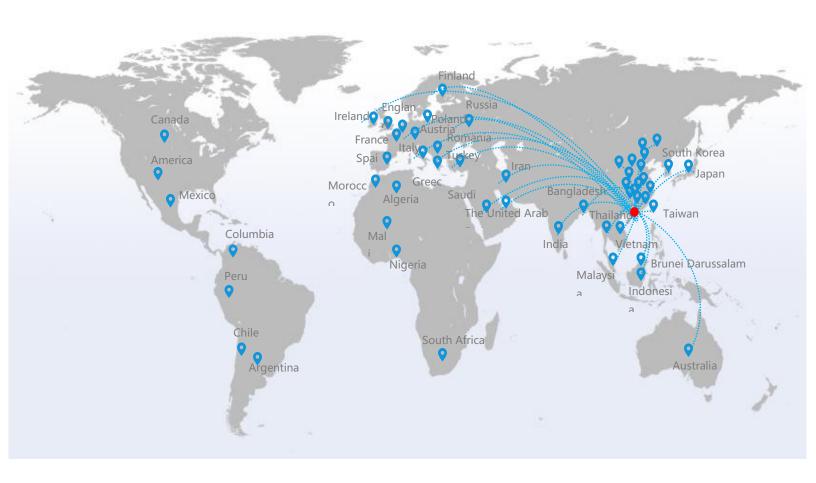
Notes:

1. Due to measurement accuracy of different single mode fibers, there could be an additional +/-1 dB fluctuation, or a +/- 3 dB total accuracy.

Outline Drawing (mm)







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Specifications & design are subject to change without prior notice.

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